

FEATURES

- Low capacitance
- Blue enhanced
- High speed
- Low dark current

DESCRIPTION

The **PDB-C203** is a blue enhanced quad-cell silicon photodiode used for nulling, centering, or measuring small positional changes packaged in a hermetic TO-5 metal package.

APPLICATIONS

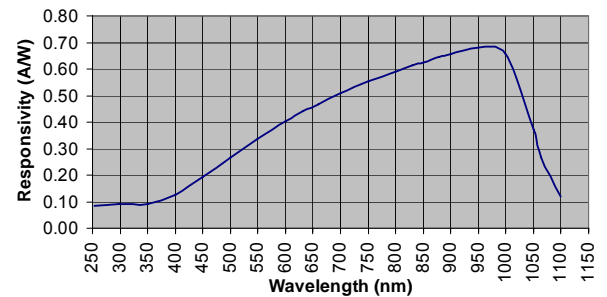
- Emitter Alignment
- Position sensing
- Medical and Industrial

ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	PARAMETER	MIN	MAX	UNITS
V_{BR}	Reverse Voltage		100	V
T_{STG}	Storage Temperature	-55	+150	°C
T_O	Operating Temperature	-40	+125	°C
T_S	Soldering Temperature*		+240	°C

* 1/16 inch from case for 3 seconds max.

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{SC}	Short Circuit Current	H = 100 fc, 2850 K	30	50		μA
I_D	Dark Current	$V_R = 5V$		0.5	1.0	nA
R_{SH}	Shunt Resistance	$V_R = 10 mV$	250	500		M Ω
C_J	Junction Capacitance	$V_R = 10 V, f = 1 MHz$		8		pF
λ_{range}	Spectral Application Range	Spot Scan	350		1100	nm
V_{BR}	Breakdown Voltage	$I = 10 \mu A$	50	75		V
NEP	Noise Equivalent Power	$V_R = 0V @ \lambda = Peak$		8.5×10^{-15}		W/ \sqrt{Hz}
t_r	Response Time**	RL = 50 $\Omega, V_R = 0 V$		190		nS
		RL = 50 $\Omega, V_R = 10 V$		13		

**Response time of 10% to 90% is specified at 660nm wavelength light.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.